

# HL63133DG

## Low Operating Current Visible High Power Laser Diode

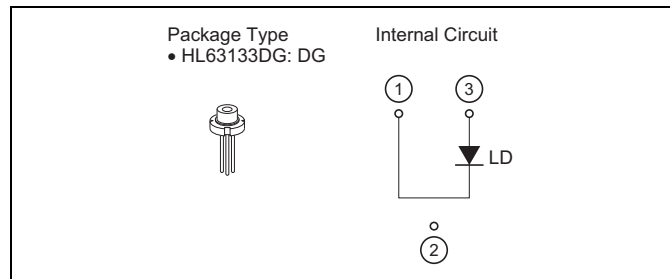
ODE2071-01 (P)  
Preliminary  
Rev.1  
Dec. 14, 2009

### Description

The HL63133DG is 0.63  $\mu\text{m}$  band AlGaInP laser diodes with a multi-quantum well (MQW) structure. It is suitable as light sources for miniature laser display, laser module and optical equipment for measurement.

### Features

- Visible light output: 637 nm Typ
- Optical output power: 170 mW CW
- Low operating current: 250 mA Typ
- Low operating voltage: 2.8 V Typ
- Small package:  $\phi 5.6\text{mm}$
- TE mode oscillation



### Absolute Maximum Ratings

( $T_C = 25^\circ\text{C}$ )

| Item                  | Symbol      | Ratings    | Unit             |
|-----------------------|-------------|------------|------------------|
| Optical output power  | $P_O$       | 170        | mW               |
| LD reverse voltage    | $V_{R(LD)}$ | 2          | V                |
| Operating temperature | $T_{opr}$   | -10 to +40 | $^\circ\text{C}$ |
| Storage temperature   | $T_{stg}$   | -40 to +85 | $^\circ\text{C}$ |

### Optical and Electrical Characteristics

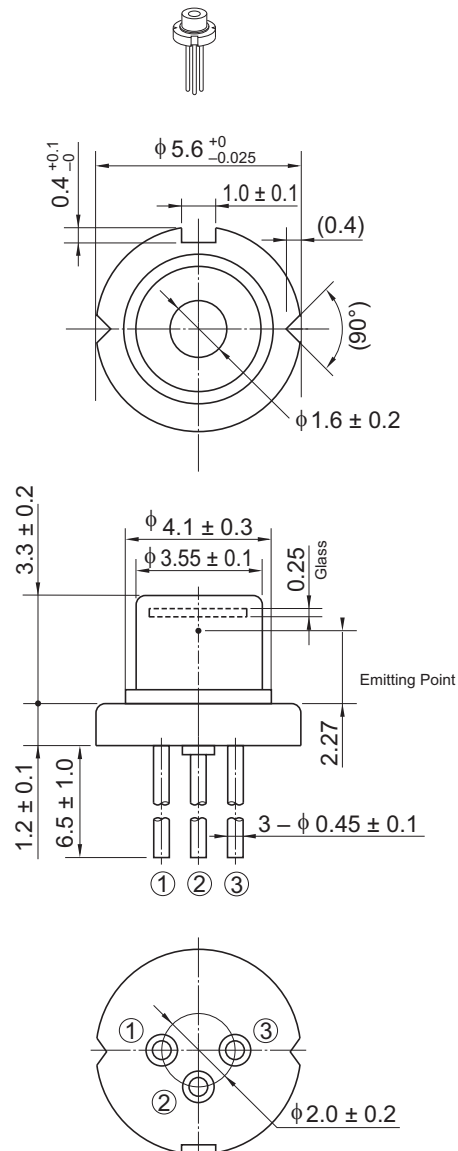
( $T_C = 25^\circ\text{C}$ )

| Item  | Symbol           | Min | Typ | Max | Unit     | Test Condition        |
|---|------------------|-----|-----|-----|----------|-----------------------|
| Threshold current                             | $I_{th}$         | —   | 60  | 90  | mA       | —                     |
| Operating current                             | $I_{OP}$         | —   | 250 | 320 | mA       | $P_O = 170\text{ mW}$ |
| Operating voltage                             | $V_{OP}$         | —   | 2.8 | 3.2 | V        | $P_O = 170\text{ mW}$ |
| Beam divergence parallel to the junction      | $\theta_{//}$    | 5   | 9   | 13  | $^\circ$ | $P_O = 170\text{ mW}$ |
| Beam divergence perpendicular to the junction | $\theta_{\perp}$ | 13  | 17  | 23  | $^\circ$ | $P_O = 170\text{ mW}$ |
| Lasing wavelength                             | $\lambda_p$      | 632 | 637 | 643 | nm       | $P_O = 170\text{ mW}$ |

Note: This is a preliminary specification. Therefore, the specification may be changed without any notice.

## Package Dimensions

Unit: mm



| OPJ Code               | LD/DG |
|------------------------|-------|
| JEDEC                  | —     |
| JEITA                  | —     |
| Mass (reference value) | 0.35g |

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1. The laser light is harmful to human body especially to eye no matter what directly or indirectly. The laser beam shall be observed or adjusted through infrared camera or equivalent.
2. This product contains gallium arsenide (GaAs), which may seriously endanger your health even at very low doses. Please avoid treatment which may create GaAs powder or gas, such as disassembly or performing chemical experiments, when you handle the product.  
When disposing of the product, please follow the laws of your country and separate it from other waste such as industrial waste and household garbage.
3. Definition of items shown in this CAS is in accordance with that shown in Opto Device Databook issued by OPJ unless otherwise specified.

## Sales Offices



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